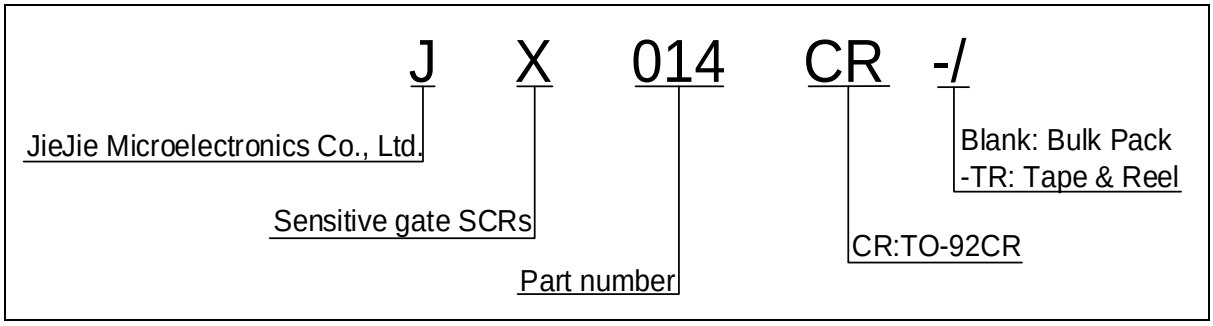
Peak gate power	P_{GM}	2	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	1	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	V_D=12V R_L=33Ω	-	50	200	μA
V_{GT}		-	0.6	0.8	V
V_{GD}	V_D=V_{DRM} T_j=110	0.2	-	-	V
I_L	I_G=1.2 I_{GT}	-	-	5	mA
I_H	I_T=0.05A	-	-	4	mA
dV/dt	V_D=800V T_j=110 R_{GK}=1kΩ	200	-	-	V/μs
	V_D=800V T_j=110 R_{GK}=220Ω	1000	-	-	

ORDERING INFORMATION



MARKING

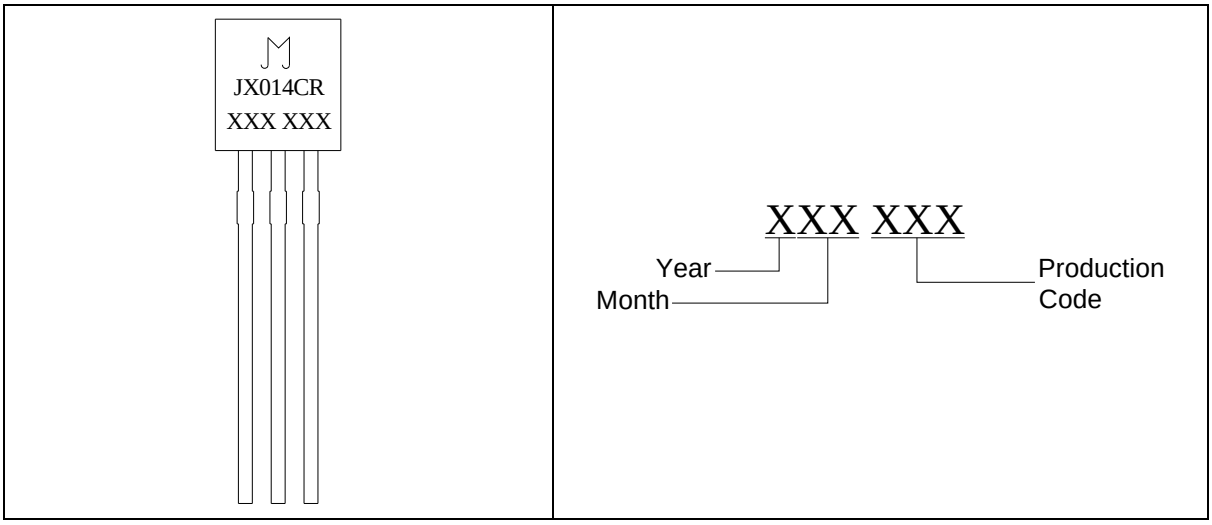
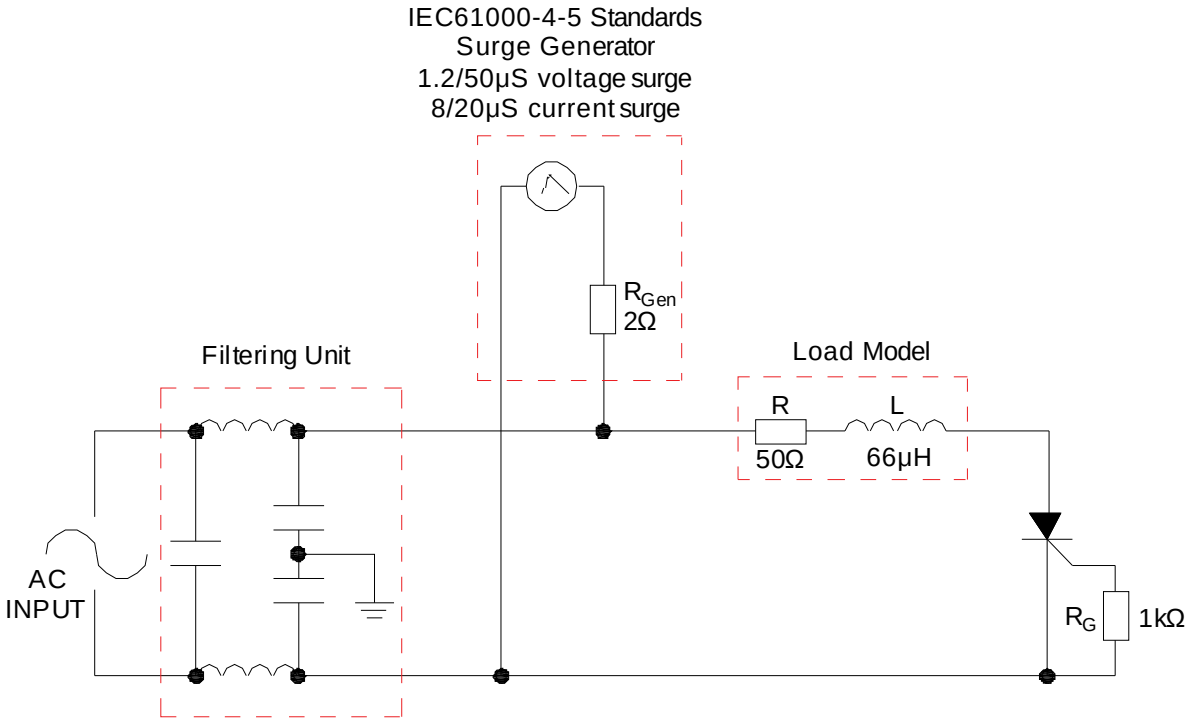


FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



LEAD FORMING AND SOLDERING

Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics

PACKAGE MECHANICAL DATA



